

isc Silicon NPN RF Transistor

BFG425W

DESCRIPTION

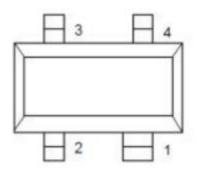
- High Power Gain
- High Current Gain Bandwidth Product
- Low Noise Figure
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for use in RF wideband amplifiers and oscillators.

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	10	V
V _{CEO}	Collector-Emitter Voltage	4.5	V
V _{EBO}	Emitter-Base Voltage	1	V
lc	Collector Current-Continuous	30	mA
lв	Base Current-Continuous	6	mA
Pc	Collector Power Dissipation	135	mW
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-65~150	°C

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)



PIN	DESCRIPTION	
1	emitter	
2	base	
3	emitter	
4	collector	



isc website: www.iscsemi.com



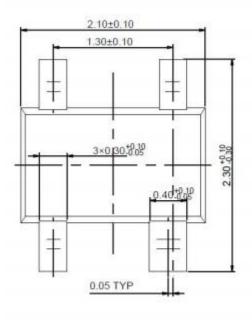
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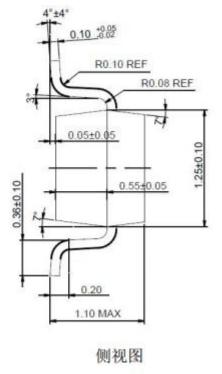
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ELECTRICAL CHARACTERISTICS

 $T_{\text{c}}\text{=}25^{\circ}\!\!^{\circ}\!\!^{\circ}_{\circ}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA ; I _B = 0	4.5			V
I _{CBO}	Collector Cutoff Current	V _{CB} = 4.5V; I _E = 0			100	nA
h _{FE}	DC Current Gain	I _C = 25mA ; V _{CE} = 2V	50	100	150	
f⊤	Transition frequency	I _C = 25mA ; V _{CE} = 2V; f= 2GHz		25		GHz
NF	Noise Figure	I _C = 2mA ; V _{CE} = 2V; f= 900MHz		0.8		dB
NF	Noise Figure	I _C = 2mA ; V _{CE} = 2V; f= 2GHz		1.2		dB
S _{21e} ²	Insertion Power Gain	Ic= 30mA ; Vce= 8V; f= 2GHz		17		dB





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